

US Patent & Trademark Office

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United States Patent Application Publication

20250257993

Kind Code

A1

Publication Date

August 14, 2025

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OPTICAL MEASUREMENT DEVICE FOR DIE BONDING ALIGNMENT

Abstract

An optical measurement device includes: a first align mark including at least one transmissive diffractive element; a second align mark apart from the first align mark in a first direction and including at least one reflective diffractive element; a beam splitter configured to reflect incident light in a direction toward the first align mark and transmit light from the first align mark; a focusing lens on a path of the light that passes through the beam splitter; and at least one image sensor configured to sense the light after the light passes through the focusing lens.

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Appl. No.: 19/045960

Filed: February 05, 2025

Foreign Application Priority Data

KR 10-2024-0019830

Feb. 08, 2024

Publication Classification

Int. Cl.: G01B11/27 (20060101)

U.S. Cl.:

CPC G01B11/272 (20130101);

Background/Summary

CROSS-REFERENCE TO RELATED APPLICATION

[0001] This application is based on and claims priority under 35 U.S.C. § 119 to Korean Patent Application No. 10-2024-0019830, filed on Feb. 8, 2024, in the Korean Intellectual Property Office, the disclosure of which is incorporated by reference herein in its entirety.

BACKGROUND

1. Field

[0002] Embodiments of the present disclosure relate to an optical measurement device for die bond alignment.

2. Description of the Related Art

[0003] The degree of integration of various integrated circuit devices, including memories, driver integrated circuits (ICs), logic devices, and image sensors, is increasing gradually, and accordingly, the size of electronic devices included therein is also reduced.

[0004] Additionally, with the development of system semiconductors, the size of chiplets and dies is gradually increasing in 2.5-dimensional (2.5D) and 3D packages, artificial intelligence (AI), and high-performance computing (HPC) semiconductor systems.

[0005] Electronic devices formed on different substrates may be packaged into one package by using an align mark provided on each substrate. A measurement method for satisfying the reduction in optical resolution required according to a decrease in a bonding pad pitch and an increase in a die size according to the development of system semiconductors is being researched.

SUMMARY

[0006] According to embodiments of the present disclosure, an optical measurement device is provided for increasing the precision of die bonding alignment when manufacturing an electronic device.

[0007] According to embodiments of the present disclosure, an optical measurement device is provided and includes: a first align mark including at least one transmissive diffractive element; a second align mark apart from the first align mark in a first direction and including at least one reflective diffractive element; a beam splitter configured to reflect incident light in a direction toward the first align mark and transmit light from the first align mark; a focusing lens on a path of the light that passes through the beam splitter; and at least one image sensor configured to sense the light after the light passes through the focusing lens.

[0008] Additional aspects will be set forth in part in the description which follows and, in part, will be apparent from the description, or may be learned by practice of the presented embodiments of the disclosure.

Description

BRIEF DESCRIPTION OF DRAWINGS

[0009] The above and other aspects, features, and advantages of certain embodiments of the present disclosure will be more apparent from the following description taken in conjunction with the accompanying drawings, in which:

[0010] FIG. 1 illustrates a schematic structure of an optical measurement device according to an embodiment;

[0011] FIG. 2A illustrates an example of structure of a first align mark provided in an optical measurement device according to an embodiment;

[0012] FIG. 2B illustrates an example of structure of a second align mark provided in an optical measurement device according to an embodiment;

[0013] FIG. 3A illustrates an example of a shape of a nanostructure that may be provided in first and second align marks of an optical measurement device according to an embodiment;
[0014] FIG. 3B illustrates an example of a shape of a nanostructure that may be provided in first and second align marks of an optical measurement device according to an embodiment;
[0015] FIG. 4 conceptually illustrates that, when using an optical measurement device according to an embodiment, arrangement positions of dies to be aligned vary depending on a size of the dies;
[0016] FIG. 5 illustrates a schematic structure of an optical measurement device according to another embodiment;
[0017] FIG. 6A illustrates an example of a change in polarization of light on a light path within the optical measurement device of FIG. 5;
[0018] FIG. 6B illustrates an example of a change in polarization of light on a light path within the optical measurement device of FIG. 5;
[0019] FIG. 7A illustrates an example of a shape of a nanostructure that may be provided in first and second align marks of the optical measurement device of FIG. 5;
[0020] FIG. 7B illustrates an example of a shape of a nanostructure that may be provided in first and second align marks of the optical measurement device of FIG. 5;
[0021] FIG. 8 illustrates a schematic structure of an optical measurement device according to an embodiment;
[0022] FIG. 9 illustrates a schematic structure of an optical measurement device according to an embodiment;
[0023] FIG. 10 illustrates a schematic structure of an optical measurement device according to an embodiment;
[0024] FIG. 11 illustrates a schematic structure of an optical measurement device according to an embodiment; and
[0025] FIG. 12 illustrates a schematic structure of an optical measurement device according to an embodiment.

DETAILED DESCRIPTION

[0026] Reference will now be made in detail to non-limiting examples of the present disclosure, with reference to the drawings, wherein like reference numerals refer to like elements throughout. In this regard, embodiments of the present disclosure may have different forms and should not be construed as being limited to the descriptions set forth herein. Accordingly, the example embodiments are merely described below, by referring to the figures, to explain example aspects. As used herein, the term “and/or” includes any and all combinations of one or more of the associated listed items. Expressions such as “at least one of,” when preceding a list of elements, modify the entire list of elements and do not modify the individual elements of the list.

[0027] In the drawings, the same reference numerals refer to the same components, and the size of each component in the drawings may be exaggerated for clarity and convenience of explanation.
[0028] It will also be understood that when an element is referred to as being “on” or “above” another element, the element may be in direct contact with the other element or other intervening elements may be present.

[0029] Terms such as “first,” “second,” etc. may be used to describe various components, but are used only for the purpose of distinguishing one component from another component. These terms do not limit the difference in material or structure of the constituent elements.

[0030] The singular forms include the plural forms unless the context clearly indicates otherwise. It should be understood that, when a part “comprises” or “includes” an element in the specification, unless otherwise defined, other elements are not excluded from the part and the part may further include other elements.

[0031] In addition, terms such as “. . . unit”, “module”, or the like refer to units that perform at least one function or operation, and the units may be implemented as hardware or software or as a combination of hardware and software.

[0032] The use of the terms “a” and “an” and “the” and similar referents in the context of describing the disclosure are to be construed to cover both the singular and the plural.

[0033] The steps comprising a method may be performed in any suitable order unless explicitly stated that they must be performed in the order described. In addition, the use of all exemplary terms (e.g., etc.) is simply for explaining example embodiments of the present discourse.

[0034] FIG. 1 illustrates a schematic structure of an optical measurement device according to an embodiment, and FIGS. 2A and 2B illustrate examples of structures of a first align mark and a second align mark provided in an optical measurement device according to an embodiment, respectively.

[0035] An optical measurement device **100** is a device that measures whether alignment is properly performed during die bonding. A die may refer to a chip, chiplet, wafer, circuit board, etc., that includes a metal pattern, semiconductor pattern, insulating pattern, or various devices to be bonded or packaged. Hereinafter, a die will simply be referred to as a substrate or die.

[0036] The optical measurement device **100** may include a first align mark **AK1** including a transmissive diffractive element, a second align mark **AK2** including a reflective diffractive element, a beam splitter **140**, a focusing lens **160**, and an image sensor **180**.

[0037] The first align mark **AK1** may be provided on a first substrate **S1**, and the second align mark **AK2** may be provided on a second substrate **S2**. According to embodiments, the first substrate **S1** and the second substrate **S2** may include device layers including a metal pattern, a semiconductor pattern, or an insulating pattern.

[0038] The first align mark **AK1** and the second align mark **AK2** are used to accurately combine elements manufactured on two separate substrates (e.g., the first substrate **S1** and the second substrate **S2**). The first align mark **AK1** and the second align mark **AK2** are arranged apart from each other in a first direction (Z direction). The first align mark **AK1** and the second align mark **AK2** may be arranged to face each other. The first align mark **AK1** and the second align mark **AK2** may not be aligned when viewed in the first direction (Z direction). For example, the first align mark **AK1** and the second align mark **AK2** may be arranged apart from each other not only in the first direction (Z direction) but also in a second direction (X) perpendicular to the first direction (Z direction) or also in a third direction (Y direction).

[0039] A beam pattern due to the first align mark **AK1** and the second align mark **AK2** varies depending on an alignment state of the first substrate **S1** and the second substrate **S2**, and the beam pattern may be detected by the image sensor **180**.

[0040] The first align mark **AK1** may include a first transmissive diffractive element **11** and a second transmissive diffractive element **12**. The first transmissive diffractive element **11** and the second transmissive diffractive element **12** may be arranged apart from each other in, for example, the second direction (X direction) perpendicular to the first direction. A spacing between the first transmissive diffractive element **11** and the second transmissive diffractive element **12** may be a spacing **p1**.

[0041] The second align mark **AK2** may include a first reflective diffractive element **21** and a second reflective diffractive element **22**. The first reflective diffractive element **21** and the second reflective diffractive element **22** may be arranged to face the first transmissive diffractive element **11** and the second transmissive diffractive element **12**, respectively. The first reflective diffractive element **21** and the second reflective diffractive element **22** may be arranged apart from each other in, for example, the second direction (X direction) perpendicular to the first direction. A spacing between the first reflective diffractive element **21** and the second reflective diffractive element **22** may be a spacing **p1**.

[0042] Here, the spacing between the first reflective diffractive element **21** and the second reflective diffractive element **22** and the spacing between the first transmissive diffractive element **11** and the second transmissive diffractive element **12** are shown to be both the spacing **p1**. However, this is an example and the spacings are not limited thereto. The spacings may be different

from each other in a range that may provide a standard for determining alignment. For example, in a state where the first substrate **S1** and the second substrate **S2** are properly aligned, the two spacings may be different in a range in which a light path may be formed, through which light that has passed through the first transmissive diffractive element **11** and enters the first reflective diffractive element **21** is reflected by the first reflective diffractive element **21** and then proceeds again toward the first transmissive diffractive element **11**.

[0043] The beam splitter **140** may reflect incident light **LE** in a direction toward the first align mark **AK1** and transmit through light from the first align mark **AK1**. The beam splitter **140** may be a half mirror that transmits a portion of the incident light **LE** and reflects another portion thereof.

[0044] The light reflected from the beam splitter **140** is directed to the first align mark **AK1**, passes through the first align mark **AK1**, and is directed to the second align mark **AK2**. Next, after being reflected from the second align mark **AK2**, the light passes through the first align mark **AK1**, enters the beam splitter **140**, passes through the beam splitter **140**, and proceeds toward the focusing lens **160**. That is, the light reflected from the beam splitter **140** sequentially passes through the first transmissive diffractive element **11**, the first reflective diffractive element **21**, and then the first transmissive diffractive element **11** or through the second transmissive diffractive element **12**, the second reflective diffractive element **22**, and then the second transmissive diffractive element **12** to be incident on the beam splitter **140**, pass through the beam splitter **140**, and proceed toward the focusing lens **160**.

[0045] The light path described above is an example is not limited thereto. For example, the light reflected from the beam splitter **140** may not pass through the first align mark **AK1**, but may instead enter the second align mark **AK2**, be reflected from the second align mark **AK2**, and then pass through the first align mark **AK1** to be incident on the beam splitter **140** and transmit through the beam splitter **140**. Alternatively, the light reflected from the beam splitter **140** may pass through the first align mark **AK1**, enter the second align mark **AK2**, be reflected from the second align mark **AK2**, and then enter the beam splitter **140** through a path that does not pass through the first align mark **AK1**, and pass through the beam splitter **140**.

[0046] The focusing lens **160** may be arranged between the image sensor **180** and the beam splitter **140**, and the image sensor **180** may be arranged at position of a focal length f of the focusing lens **160**.

[0047] In other embodiments, the position of the image sensor **180** may be different. For example, a magnifying optical system such as a relay lens may be located between the image sensor **180** and the focusing lens **160**. In this case, the magnifying optical system may be arranged at the position of the focal length f of the focusing lens **160**.

[0048] A distance $d1$ between the focusing lens **160** and the first substrate **S1** may be determined such that, while the first substrate **S1** and the second substrate **S2** are aligned with each other, light that has passed through the first align mark **AK1** and the second align mark **AK2** is directed toward a center of the focusing lens **160**. However, this is an example, and the distance $d1$ and the spacing $p1$ between the first transmissive diffractive element **11** and the second transmissive diffractive element **12** may be determined based on other standards.

[0049] The optical measurement device **100** of an embodiment forms infinite-focused optics and, therefore, there is little difference in measurement precision depending on the die size.

[0050] The first align mark **AK1** and the second align mark **AK2** may be elements based on (e.g., formed of) nanostructures.

[0051] Referring to FIG. 2A, the first transmissive diffractive element **11** and the second transmissive diffractive element **12** included in the first align mark **AK1** may each include a plurality of first nanostructures **NS1**.

[0052] The shape and arrangement of the first nanostructures **NS1** may be determined such that the first align mark **AK1** operates as a transmissive diffractive element. The first transmissive diffractive element **11** and the second transmissive diffractive element **12** may be meta-lenses. The

first transmissive diffractive element **11** and the second transmissive diffractive element **12** may be meta-deflectors such as, for example, a transmissive meta-deflector. The first transmissive diffractive element **11** and the second transmissive diffractive element **12** may be lenses that also function as deflectors. In this case, the first transmissive diffractive element **11** and the second transmissive diffractive element **12** may have different light deflecting directions and the same refractive power as each other. However, embodiments of the present disclosure are not limited thereto.

[0053] Referring to FIG. 2B, the first reflective diffractive element **21** and the second reflective diffractive element **22** included in the second align mark AK2 may each include a plurality of second nanostructures NS2.

[0054] The shape and arrangement of the second nanostructures NS2 may be determined such that the second align mark AK2 operates as a reflective diffractive element. The first reflective diffractive element **21** and the second reflective diffractive element **22** may be meta-mirrors. The first reflective diffractive element **21** and the second reflective diffractive element **22** may be meta-deflectors such as, for example, a reflective meta-deflector. The first reflective diffractive element **21** and the second reflective diffractive element **22** may be meta-mirrors or meta-deflectors having refractive power. The first reflective diffractive element **21** and the second reflective diffractive element **22** may be reflective meta-deflectors having refractive power. In this case, directions in which the first reflective diffractive element **21** and the second reflective diffractive element **22** deflect light may be different from each other. However, embodiments of the present disclosure are not limited thereto.

[0055] The first nanostructures NS1 and the second nanostructures NS2 each independently have a sub-wavelength shape dimension, that is, a shape dimension smaller than a center wavelength of an operating wavelength band. Arrangement pitches of the first nanostructures NS1 and the second nanostructure NS2 may also be a sub-wavelength, or may be equal to or less than $\frac{2}{3}$ of the center wavelength of the operating wavelength band. Heights of the first nanostructure NS1 and the second nanostructure NS2 may range from a sub-wavelength to a wavelength or more.

[0056] The first nanostructures NS1 and the second nanostructures NS2 may each independently include a metal or a high refractive index material. The first nanostructures NS1 and the second nanostructures NS2 may include Cu, W, or TiN, or other various metal materials, or, c-Si, p-Si, a-Si, Group III-V compound semiconductors (GaAs, GaP, GaN, etc.), SiC, SiO₂, TiO₂, or SiN.

[0057] FIGS. 3A and 3B illustrate examples of shapes of nanostructures that may be respectively provided in first and second align marks of an optical measurement device according to an embodiment.

[0058] The first nanostructures NS1 and the second nanostructures NS2 may each independently have a cylindrical shape with a diameter of length D and a height of length H as illustrated in FIG. 3A, or a square pillar shape with one side of length D and a height of length H as illustrated in FIG. 3B.

[0059] The first nanostructures NS1 may all have the same height, and the length D may be set differently depending on the relative positions of each of the first nanostructures NS1 within the first align mark AK1. As described above, a desired phase profile may be implemented by adjusting the size of the first nanostructures NS1 depending on the position. For example, a cross-sectional size, length D, of each first nanostructure NS1 may be determined such that the first transmissive diffractive element **11** and the second transmissive diffractive element **12** each function as a meta-lens having a desired refractive power and effective diameter or a meta-deflector having a desired directivity. However, the first nanostructures NS1 are not limited to all having the same height of length H. The heights of the first nanostructures NS1 included in the first transmissive diffractive element **11** and the heights of the first nanostructures NS1 included in the second transmissive diffractive element **12** may be different from each other, and the heights of the first nanostructures

NS1 may also be different within the first transmissive diffractive element **11** or the second transmissive diffractive element **12**.

[0060] All of the second nanostructures NS2 may have the same height, and length D may be set differently depending on the relative positions of the second nanostructures NS2 within the second align mark AK2 where each of the second nanostructures NS2 is arranged. As described above, a desired phase profile may be implemented by adjusting the size of the second nanostructures NS2 depending on the relative positions of each of the second nanostructures NS2. For example, a cross-sectional size, length D, of each second nanostructure NS2 may be determined such that the first reflective diffractive element **21** and the second reflective diffractive element **22** may each function as a meta-lens having a desired refractive power and effective diameter or a meta-deflector having a desired directivity.

[0061] The nanostructures illustrated in FIGS. 3A and 3B are illustrated as having a cross-sectional shape perpendicular to the first direction (Z direction) and symmetrical with respect to at least two axial directions (X direction, Y direction), but are not limited thereto. For example, nanostructures may have cross-sectional shapes with different lengths in the X direction and the Y direction. These nanostructures may have the same size, and the arrangement angle thereof may be set according to the relative positions thereof within the first align mark AK1 and the second align mark AK2 so as to realize a desired phase profile.

[0062] The transmissive diffractive elements and the reflective diffractive elements constituting the first align mark AK1 and the second align mark AK2 are not limited to the form including the illustrated nanostructures. The transmissive diffractive elements and the reflective diffractive elements constituting the first align mark AK1 and the second align mark AK2 may include, for example, various micro-patterns capable of diffracting, reflecting, or scattering light.

[0063] FIG. 4 conceptually illustrates that, when using an optical measurement device according to an embodiment, arrangement positions of dies to be aligned vary depending on a size of the dies.

[0064] When aligning a third substrate S3 and a fourth substrate S4 that have different sizes from the first substrate S1 and the second substrate S2, locations at which the third substrate S3 and the fourth substrate S4 are arranged may be different from the locations where the first substrate S1 and the second substrate S2 are arranged.

[0065] The third substrate S3 may be larger than the first substrate S1, for example, larger in the X direction. In this case, for alignment measurement, the location where the third substrate S3 is arranged may be different from the location where the first substrate S1 is arranged. That is, a distance d2 between the third substrate S3 and the focusing lens **160** may be different from the distance d1 between the first substrate S1 and the focusing lens **160**.

[0066] As illustrated, when the third substrate S3 is larger than the first substrate S1, the distance d2 may be larger than the distance d1. Additionally, a spacing p2 between the first transmissive diffractive element **11** and the second transmissive diffractive element **12** provided in the third substrate S3 may also be different from the spacing p1.

[0067] The relationship between the distance d2 and the spacing p2 may be almost identical or similar to the relationship between the distance d1 and the spacing p1. For example, $d2/p2=d1/p1$, or $d2/p2=d1/p1$. The detailed criteria by which the distance d1, the distance d2, the spacing p1, and the spacing p2 are defined may change to some extent. In the drawing, the spacing p1 or the spacing p2 is indicated as the spacing between the first transmissive diffractive element **11** and the second transmissive diffractive element **12**, but may also be defined as a distance between a center of the first transmissive diffractive element **11** and the second transmissive diffractive element **12**. the distance d1 and the distance d2 may be defined as a distance from a center of the focusing lens **160** to the first align mark AK1 arranged on the first substrate S1 and a distance from a center of the focusing lens **160** to the first align mark AK1 arranged on the third substrate S3, respectively.

[0068] As described above, even if the size of a die increases, the optical measurement device **100** according to the embodiment may measure alignment with the same precision by adjusting the

arrangement position of the die.

[0069] FIG. 5 illustrates a schematic structure of an optical measurement device according to another embodiment. FIGS. 6A and 6B illustrate examples of changes in polarization of light while light passes by a transmissive diffractive element and a reflective diffractive element provided in each of a first align mark and a second align mark of the optical measurement device of FIG. 5. [0070] An optical measurement device **101** according to an embodiment of the present disclosure is different from the optical measurement device **100** of FIG. 1 in that the optical measurement device **101** includes a polarization beam splitter **141** for splitting incident light according to polarization, and a first align mark **AK3** and a second align mark **AK4** that are designed to be suitable for operation with respect to polarized light.

[0071] The polarization beam splitter **141** may exhibit different transmission and reflection effects for light of first polarization and second polarization which are different from each other. The first polarization and the second polarization may be linear polarization perpendicular to each other. The polarization beam splitter **141** may reflect light of a first polarization (e.g., S polarization), and transmit a second polarization perpendicular thereto (e.g., P polarization).

[0072] The first align mark **AK3** and the second align mark **AK4** are similar to the first align mark **AK1** and the second align mark **AK2** of FIG. 1, respectively, as the first align mark **AK3** and the second align mark **AK4** include a transmissive diffractive element and a reflective diffractive element, respectively. The first align mark **AK3** and the second align mark **AK4** are different from the first align mark **AK1** and the second align mark **AK2** in FIG. 1 in that a first transmissive diffractive element **13** and a second transmissive diffractive element **14**, which form the first align mark **AK3**, and a first reflective diffractive element **23** and a second reflective diffractive element **33**, which form the second align mark **AK4**, each include nanostructures, the shape and arrangement of which are determined to transmit or reflect S-polarized light.

[0073] When the incident light **LE** is S-polarized light, most of the incident light **LE** incident on the polarization beam splitter **141** is reflected and proceeds toward the first align mark **AK3**. After the incident light **LE** sequentially passes through the first transmissive diffractive element **13** of the first align mark **AK3**, is reflected by the first reflective diffractive element **23** of the second align mark **AK4**, passes through the first transmissive diffractive element **13** of the first align mark **AK3**, and is incident on the polarization beam splitter **141** again, the light may be in a P polarization state. As described above, most of the incident P-polarized light passes through the polarization beam splitter **141** and is directed to the focusing lens **160**.

[0074] The light path described above is described as passing through the first transmissive diffractive element **13**, reflecting from the first reflective diffractive element **23**, and passing through the first transmissive diffractive element **13** again, but is not limited thereto. Light reflected from the polarization beam splitter **141** may re-enter the polarization beam splitter **141** after sequentially reflecting from the first reflective diffractive element **23** and passing through the first transmissive diffractive element **13**, or may re-enter the polarization beam splitter **141** after sequentially passing through the first transmissive diffractive element **13** and reflecting from the first reflective diffractive element **23**.

[0075] On these light paths, little light loss occurs due to the polarization beam splitter **141**, which may be advantageous for sensing sensitivity in the image sensor **180**. For example, in a case of the beam splitter **140** that is a half mirror, such as the optical measurement device **100** of FIG. 1, light loss by $\frac{1}{2}$ occurs every time the light passes the beam splitter **140**, and the amount of light that reaches the image sensor **180** is equal to or less than $\frac{1}{4}$ of the amount of light provided.

[0076] An example of a change in polarization while passing through the first align mark **AK3**, reflecting from the second align mark **AK4**, and re-passing through the first align mark **AK3** is as follows with reference to FIGS. 6A and 6B.

[0077] Referring to FIG. 6A, the first transmissive diffractive element **13** and the first reflective diffractive element **23** may be designed to operate as a transmissive element and a reflective

element, respectively, both for S-polarized light, and the change in polarization does not occur in the first transmissive diffractive element **13** and occurs only in the first reflective diffractive element **23**.

[0078] The first transmissive diffractive element **13** may operate as a transmissive diffractive element such as, for example, a meta-lens or a meta-deflector for S-polarized light, and may be designed not to cause a change in polarization of the incident light occurs.

[0079] The first reflective diffractive element **23** may operate as a reflective element such as, for example, a meta-mirror or a meta-deflector, for S-polarized light, and may also be designed to reflect the light with changing the polarization of the incident light from S-polarization to P-polarization.

[0080] Referring to FIG. **6B**, a $\frac{1}{4}$ wave plate **50** may be further arranged between the polarization beam splitter **141** and the first transmissive diffractive element **13**. The $\frac{1}{4}$ wave plate **50** may convert incident S-polarized light into left-circularly polarized light L. The first transmissive diffractive element **13** and the first reflective diffractive element **23** may be designed to operate as a transmissive element or a reflective element, respectively, both for S-polarized light, and may be designed such that polarization conversion does not occur in the first transmissive diffractive element **13**, but only in the first reflective diffractive element **23**.

[0081] The first transmissive diffractive element **13** may operate as a transmissive diffractive element such as, for example, a meta-lens or a meta-deflector for left-circularly polarized light L, and may be designed not to convert the polarization of the incident light.

[0082] The first reflective diffractive element **23** may operate as a reflective element such as, for example, a meta-mirror or a meta-deflector for the incident left-circularly polarized light L, and may be designed to reflect the left-circularly polarized light L as the left-circularly polarized light L.

[0083] The light path described above is described as passing through the first transmissive diffractive element **13**, reflecting from the first reflective diffractive element **23**, and passing through the first transmissive diffractive element **13**, but is not limited thereto. Light that is reflected from the polarization beam splitter **141** and has passed through the $\frac{1}{4}$ wave plate **50** may re-enter the $\frac{1}{4}$ wave plate **50** again after sequentially reflecting from the first reflective diffractive element **23** and passing through the first transmissive diffractive element **13**, or may re-enter the $\frac{1}{4}$ wave plate **50** by sequentially passing through the first transmissive diffractive element **13** and reflecting from the first reflective diffractive element **23**.

[0084] As described above, nanostructures having an asymmetric shape may be used for the first align mark **AK3** and the second align mark **AK4** that act on polarized light. At least one from among the first align mark **AK3** and the second align mark **AK4** may include a nanostructure having an asymmetric shape.

[0085] FIGS. **7A** and **7B** illustrate examples of shapes of nanostructures that may be respectively provided in first and second align marks of the optical measurement device of FIG. **5**.

[0086] A cross-sectional shape of the nanostructures provided in the first align mark **AK3** or the second align mark **AK4** may have an asymmetry of 2-fold or more. The nanostructures may independently have a pillar shape with an asymmetric cross-section where a major axis and a minor axis are defined. For example, as illustrated in FIG. **7A**, the nanostructures may have a cross-section of an elliptical pillar shape having a length D_x in a major axis direction and a length D_y in a minor axis direction, the length D_x and the length D_y being different from each other.

Alternatively, the nanostructures may have a cross-section of a rectangular pillar shape having a length D_x in a major axis direction and a length D_y in a minor axis direction, the length D_x and the length D_y being different from each other.

[0087] FIG. **8** illustrates a schematic structure of an optical measurement device according to an embodiment.

[0088] An optical measurement device **102** according to an embodiment of the present disclosure

differs from the optical measurement device **101** of FIG. **5** in that a polarizer **150** is further provided to provide polarized light to the polarization beam splitter **141**.

[0089] FIG. **9** illustrates a schematic structure of an optical measurement device according to an embodiment.

[0090] The optical measurement device **103** according to an embodiment of the present disclosure may include an aperture stop **170** that blocks a portion of the light incident on the image sensor **180**. The aperture stop **170** includes an opening in the periphery thereof except a center thereof. For example, the aperture stop **170** may block some of light directed toward the center thereof among light incident on the image sensor **180**.

[0091] An area where light is blocked by the aperture stop **170** may be an area at a position where beams from the first align mark **AK1** and the second align mark **AK2** are not focused. By blocking light from entering this area, saturation of a circuit during a photoelectric conversion operation of the image sensor **180** may be prevented.

[0092] FIG. **10** illustrates a schematic structure of an optical measurement device according to an embodiment.

[0093] The optical measurement device **104** according to an embodiment of the present disclosure is different from the optical measurement device **100** of FIG. **1** in that the optical measurement device **104** includes two image sensors **181** and **182** arranged apart from each other.

[0094] Similar to the concept of including the aperture stop **170** in the optical measurement device **103** of FIG. **9**, instead of using the aperture stop **170**, the optical measurement device **104** includes two image sensors **181** and **182** arranged apart from each other in order that light directed to certain positions is not detected.

[0095] FIG. **11** illustrates a schematic structure of an optical measurement device according to an embodiment.

[0096] An optical measurement device **105** according to an embodiment of the present disclosure differs from the optical measurement device **100** of FIG. **1** in that a relay optical system **120** is further provided between the focusing lens **160** and the image sensor **180**.

[0097] The relay optical system **120** may be arranged at a position of a focal distance f of the focusing lens **160** and may include, for example, a pair of relay lenses. The relay optical system **120** may provide an enlarged image to the image sensor **180**.

[0098] FIG. **12** illustrates a schematic structure of an optical measurement device according to an embodiment.

[0099] An optical measurement device **106** may include a light source **110**, a beam splitter **140**, a first substrate **S1** including a first align mark, a second substrate **S2** including a second align mark, a focusing lens **160**, and an image sensor **180**.

[0100] The light source **110** provides light to the beam splitter **140**. A collimating lens may be further arranged between the light source **110** and the beam splitter **140** to provide collimated light to the beam splitter **140**. Alternatively, this collimating lens may be included in the light source **110**.

[0101] The image sensor **180** may detect a beam pattern that is formed after light from the light source **110** is reflected by the beam splitter **140** and passes through the first substrate **S1**, is reflected from the second substrate **S2**, and passes through the first substrate **S1**. For example, the beam pattern may be a beam pattern formed after light has passed through the first align mark **AK1** of the first substrate **S1**, is reflected from the second align mark **AK2** of the second substrate **S2**, and then passes through the first align mark **AK1** of the first substrate **S1** or a beam pattern formed after light has sequentially reflected from the second align mark **AK2** of the second substrate **S2** and passes through the first align mark **AK1** of the first substrate **S1**, or a beam pattern formed after light has sequentially passed through the first align mark **AK1** of the first substrate **S1** and is reflected from the second align mark **AK2** of the second substrate **S2**.

[0102] The optical measurement device **106** may further include a processor **190**, and the processor

190 may analyze a degree of alignment between the first substrate **S1** and the second substrate **S2** according to a beam pattern sensed by the image sensor **180**. That is, through comparison with a beam pattern that appears when the first substrate **S1** and the second substrate **S2** are properly aligned, whether the first substrate **S1** and the second substrate **S2** are aligned with each other or a degree of misalignment may be analyzed.

[0103] The processor **190** may also control the overall operation of the optical measurement device **106**.

[0104] According to embodiments of the present disclosure, the processor **190** may include (or be provided with) memory storing computer code that is configured to, when executed by the processor **190**, cause the processor **190** to perform its functions.

[0105] The optical measurement device **106** may further include a driving unit **195** (e.g., an actuator) and may move either the first substrate **S1** or the second substrate **S2** due to control by the processor **190**. For example, one from among the first substrate **S1** and the second substrate **S2** may be fixed, and the other one may be arranged on a driving stage and the position thereof may be adjusted by the driving unit **195**.

[0106] The optical measurement devices **103**, **104**, **105**, and **106** of FIGS. **9** to **12** have a modified structure from the optical measurement device **100** of FIG. **1**, but are an example. As with the optical measurement devices **101** and **102** of FIGS. **5** and **8**, the modifications described above may be applied also when the first align mark **AK3** and the second align mark **AK4** including the polarization beam splitter **141** and designed in consideration of polarization.

[0107] The optical measurement devices described above have been described with reference to example embodiments illustrated in the drawings, but these are merely examples, and it will be understood to those skilled in the art that various modifications and other equivalent embodiments may be made therefrom without departing from the scope of the present disclosure. The described embodiments should be considered in a descriptive sense only and not for purposes of limitation.

[0108] By using the optical measurement device, alignment errors may be precisely measured during die bonding in various electronic device manufacturing processes.

[0109] The optical measurement devices described above may have almost no limitations in measuring alignment errors depending on the die size.

[0110] It should be understood that embodiments described herein should be considered in a descriptive sense only and not for purposes of limitation. Descriptions of features or aspects within each embodiment should typically be considered as available for other similar features or aspects in other embodiments. While one or more embodiments have been described with reference to the figures, it will be understood by those of ordinary skill in the art that various changes in form and details may be made therein without departing from the spirit and scope of the present disclosure.

Claims

1. An optical measurement device comprising: a first align mark comprising at least one transmissive diffractive element; a second align mark apart from the first align mark in a first direction and comprising at least one reflective diffractive element; a beam splitter configured to reflect incident light in a direction toward the first align mark and transmit light from the first align mark; a focusing lens on a path of the light that passes through the beam splitter; and at least one image sensor configured to sense the light after the light passes through the focusing lens.
2. The optical measurement device of claim 1, wherein the at least one image sensor is at a position of a focal distance of the focusing lens.
3. The optical measurement device of claim 1, wherein the at least one transmissive diffractive element is a plurality of transmissive elements comprising a first transmissive diffractive element and a second transmissive diffractive element apart from each other in a second direction perpendicular to the first direction.

4. The optical measurement device of claim 3, wherein the at least one reflective diffractive element is a plurality of diffractive elements comprising: a first reflective diffractive element apart from the first transmissive diffractive element in the first direction, and a second reflective diffractive element apart from the second transmissive diffractive element in the first direction.
 5. The optical measurement device of claim 1, wherein the at least one transmissive diffractive element comprises a meta-lens or a meta-deflector, and the meta-lens or the meta-deflector comprises a plurality of nanostructures.
 6. The optical measurement device of claim 1, wherein the at least one reflective diffractive element comprises a meta-mirror or a meta-deflector, and the meta-mirror or the meta-deflector comprises a plurality of nanostructures.
 7. The optical measurement device of claim 1, wherein the beam splitter comprises a half mirror.
 8. The optical measurement device of claim 1, wherein the beam splitter comprises a polarization beam splitter that is configured to reflect light of a first polarization and transmit light of a second polarization perpendicular to the first polarization.
 9. The optical measurement device of claim 8, wherein the at least one reflective diffractive element is configured to reflect the light having the first polarization, that is previously reflected from the polarization beam splitter, with the second polarization.
 10. The optical measurement device of claim 8, further comprising a $\frac{1}{4}$ wave plate between the polarization beam splitter and the first align mark.
 11. The optical measurement device of claim 8, wherein the at least one transmissive diffractive element and the at least one reflective diffractive element each comprise a plurality of nanostructures, and a cross-sectional shape of at least some of the plurality of nanostructures, in a second direction perpendicular to the first direction, has an asymmetry of 2-fold or more.
 12. The optical measurement device of claim 8, further comprising a polarizer at one side of the polarization beam splitter and configured to convert polarization of the incident light into the first polarization.
 13. The optical measurement device of claim 1, further comprising an aperture stop between the at least one image sensor and the focusing lens, the aperture stop configured to block a portion of the light from being incident on the at least one image sensor.
 14. The optical measurement device of claim 1, wherein the at least one image sensor is a plurality of image sensors comprising a first image sensor and a second image sensor that are apart from each other in a second direction perpendicular to the first direction.
 15. The optical measurement device of claim 1, further comprising a relay optical system between the focusing lens and the at least one image sensor, wherein the relay optical system is at a position of a focal distance of the focusing lens.
 16. The optical measurement device of claim 1, further comprising a light source that is configured to provide light incident on the beam splitter.
 17. The optical measurement device of claim 1, wherein the first align mark is on a first substrate, and the second align mark is on a second substrate that is different from the first substrate.
 18. The optical measurement device of claim 17, further comprising a processor that is configured to analyze an alignment state of the first substrate and the second substrate according to a beam pattern sensed by the at least one image sensor.
 19. The optical measurement device of claim 18, further comprising an actuator configured to move at least one from among the first substrate and the second substrate according to control by the processor.
 20. The optical measurement device of claim 1, wherein the at least one transmissive diffractive element and the at least one reflective diffractive element each comprise a plurality of nanostructures.
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